To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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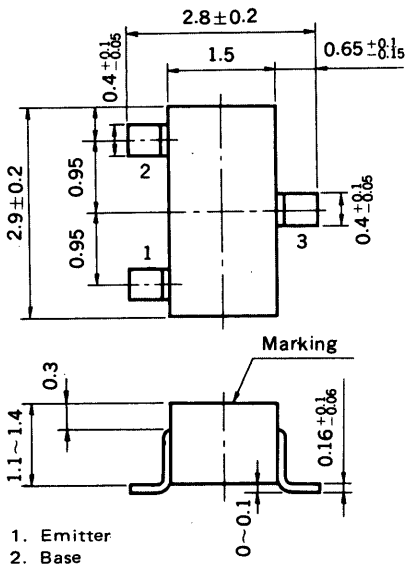
DATA SHEET

RENESAS

SILICON TRANSISTOR
2SC3739

HIGH FREQUENCY AMPLIFIER AND SWITCHING
NPN SILICON EPITAXIAL TRANSISTOR
MINI MOLD

PACKAGE DIMENSIONS
in millimeters



1. Emitter
2. Base
3. Collector

FEATURES

- High Gain Bandwidth Product: f_T = 200 MHz MIN.
- Complementary to 2SA1464

ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Current (T_a = 25 °C)

Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	40	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current (DC)	I_C	500	mA
Maximum Power Dissipation			
Total Power Dissipation			
at 25 °C Ambient Temperature	P_T	200	mW
Maximum Temperatures			
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	−55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CBO}			100	nA	V_{CB} = 40 V, I_E = 0
Emitter Cutoff Current	I_{EBO}			100	nA	V_{EB} = 4.0 V, I_C = 0
DC Current Gain	h_{FE1}	75	150	300		V_{CE} = 1.0 V, I_C = 150 mA
DC Current Gain	h_{FE2}	20	75			V_{CE} = 2.0 V, I_C = 500 mA
Collector Saturation Voltage	$V_{CE(sat)}$		0.25	0.75	V	I_C = 500 mA, I_B = 50 mA
Base Saturation Voltage	$V_{BE(sat)}$		1.0	1.2	V	I_C = 500 mA, I_B = 50 mA
Gain Bandwidth Product	f_T	200	400		MHz	V_{CE} = 10 V, I_E = −20 mA
Output Capacitance	C_{ob}		3.5	8.0	pF	V_{CB} = 10 V, I_E = 0, f = 1.0 MHz
Turn-on Time	t_{on}			35	ns	V_{CC} = 30 V
Storage Time	t_{stg}			225	ns	I_C = 150 mA
Turn-off Time	t_{off}			275	ns	I_{B1} = −I_{B2} = 15 mA

* Pulsed: PW ≦ 350 μs, Duty Cycle ≦ 2 %

h_{FE} Classification

Marking	B12	B13	B14
h_{FE1}	75 to 150	100 to 200	150 to 300

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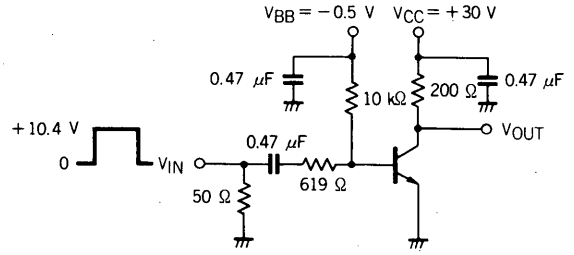
Date Published November 1989 M
Printed in Japan

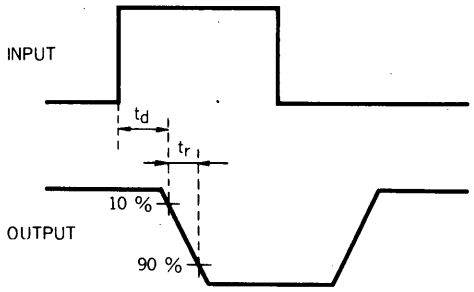
SWITCHING TIME TEST CIRCUIT



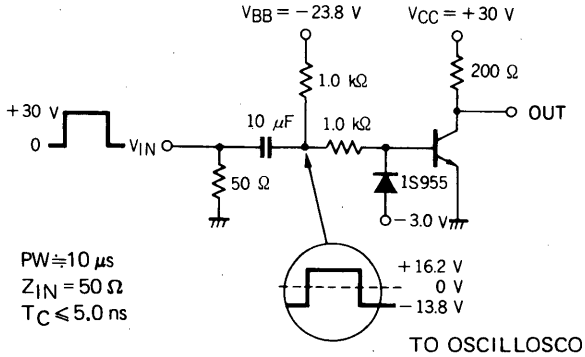
PW ≤ 200 ns
$t_r \leq 2.0$ ns
$Z_{IN} = 50\ \Omega$

TO OSCILLOSCOPE
$Z_{IN} > 100\ k\Omega$
$C_{IN} \leq 12$ pF
$t_r < 5.0$ ns

t_{on} SWITCHING



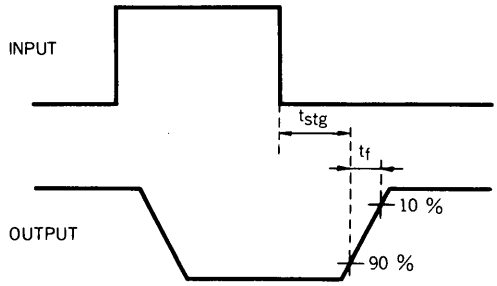
VOLTAGE WAVEFORMS



PW ≒ 10 μs
$Z_{IN} = 50\ \Omega$
$T_C \leq 5.0$ ns

TO OSCILLOSCOPE
$Z_{IN} > 100\ k\Omega$
$C_{IN} \leq 12$ pF
$t_r < 5.0$ ns

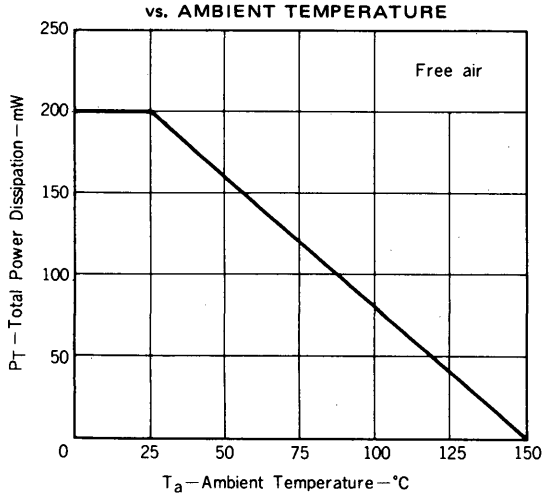
t_{off} SWITCHING



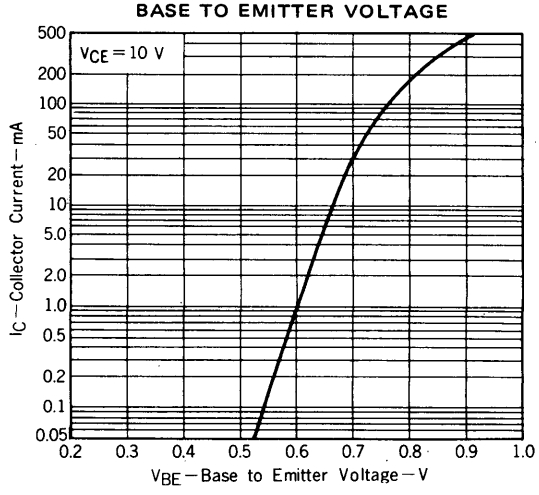
VOLTAGE WAVEFORMS

TYPICAL CHARACTERISTICS ($T_a = 25$ °C)

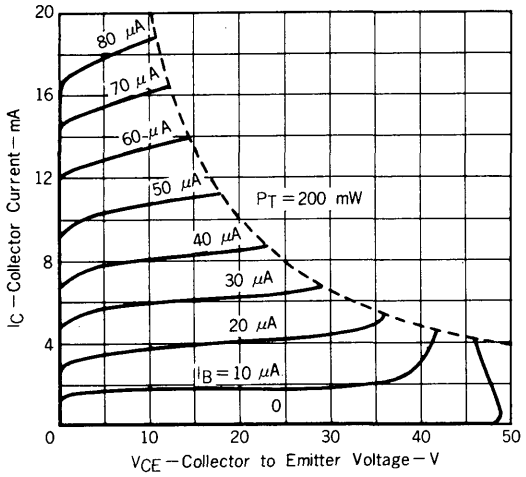
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



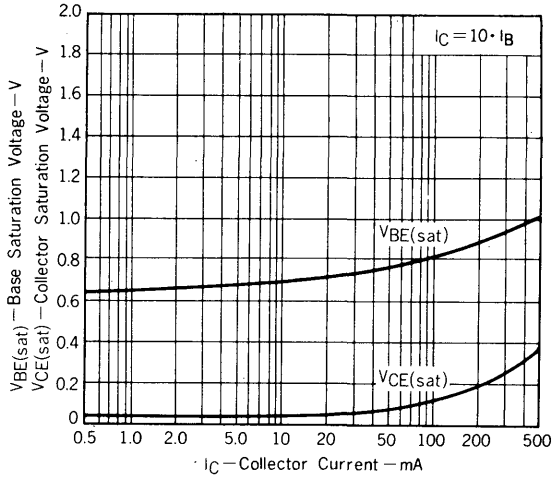
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



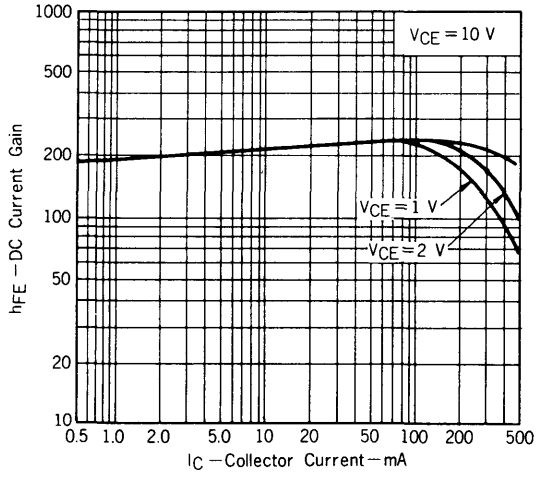
COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE



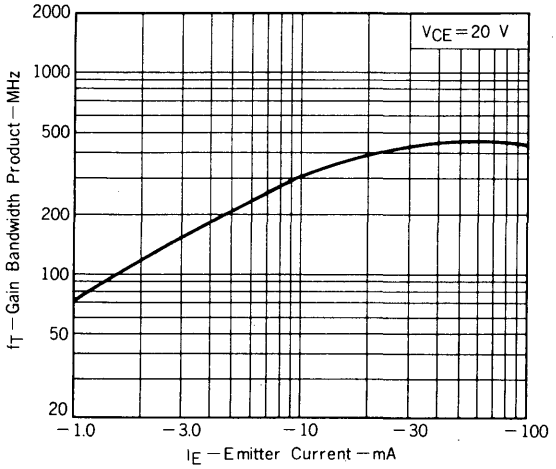
COLLECTOR AND BASE SATURATION VOLTAGE
vs. COLLECTOR CURRENT



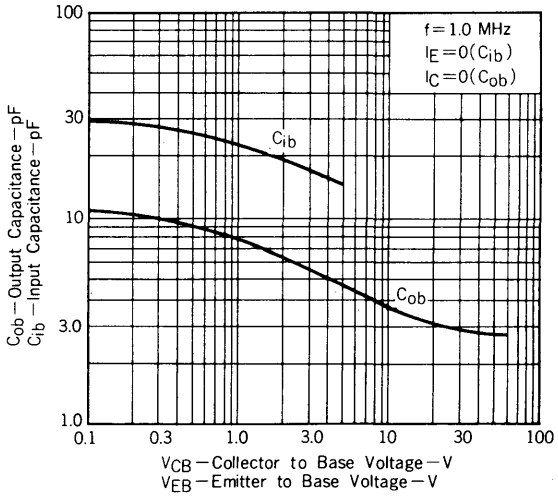
DC CURRENT GAIN vs.
COLLECTOR CURRENT



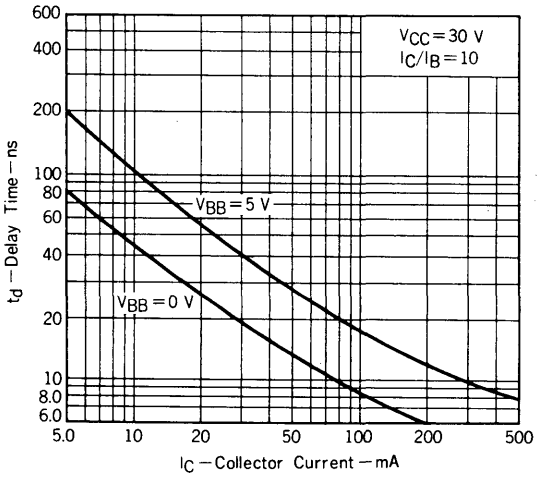
GAIN BANDWIDTH PRODUCT
vs. EMITTER CURRENT



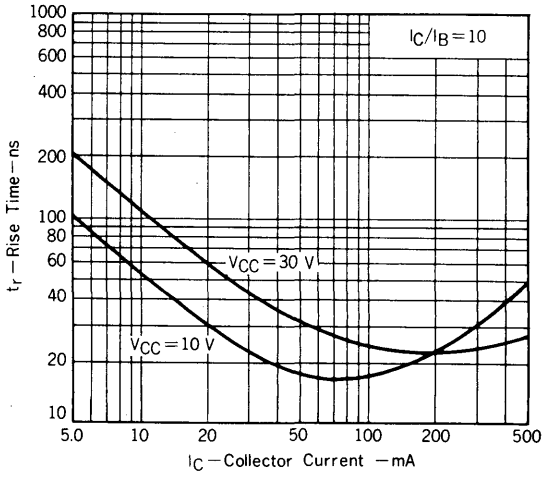
INPUT AND OUTPUT CAPACITANCE
vs. REVERSE VOLTAGE



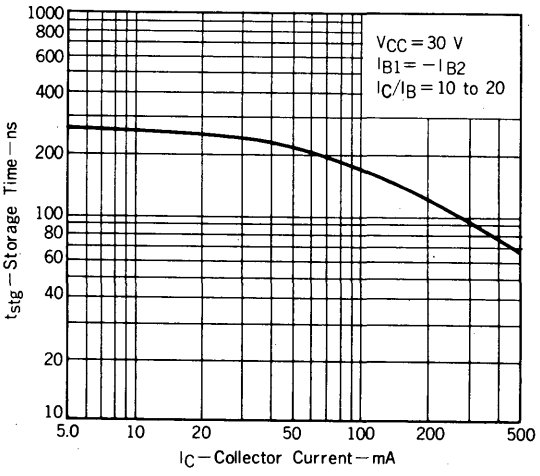
DELAY TIME vs.
COLLECTOR CURRENT



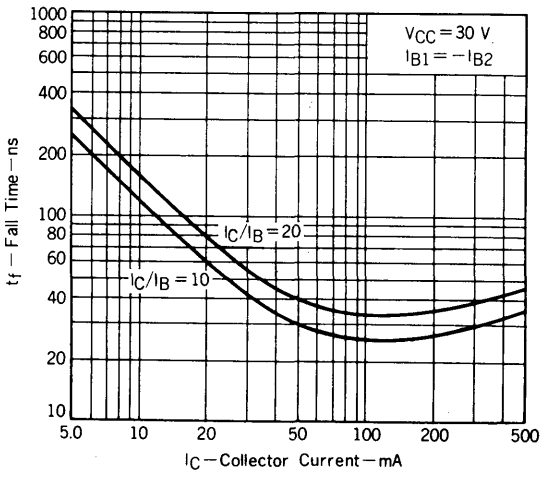
RISE TIME vs.
COLLECTOR CURRENT



STORAGE TIME vs.
COLLECTOR CURRENT



FALL TIME vs.
COLLECTOR CURRENT



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